US 20240237410A9

(54) **OLED DISPLAY PANEL AND MANUFACTURING METHOD THEREOF**

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(57)   **ABSTRACT**

An organic light emitting diode (OLED) display panel includes a substrate, a thin film transistor (TFT) layer, a planarization layer, and a pixel definition layer which are arranged in sequence. The planarization layer is provided with first via holes, and the pixel definition layer is provided with second via holes and a through hole. Each first via holes communicates with one of the second via holes. The OLED display panel further includes a light-emitting device layer. The light-emitting device layer includes an anode, a light-emitting layer, and a cathode sequentially arranged on one side of the planarization layer. The light-emitting layer is arranged in the through hole. The cathode covers the pixel definition layer, the first via hole, the second via hole, and the light-emitting layer.